

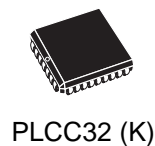
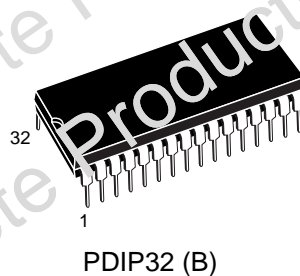
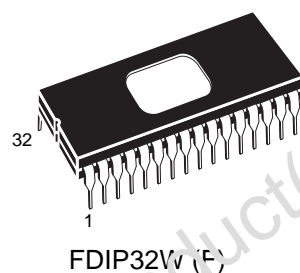


**THE DATASHEET OF  
M27W801-100N6**



**8 Mbit (1Mb x8) low voltage UV EPROM and OTP EPROM****Feature summary**

- 2.7V to 3.6V supply voltage in READ operation
- Access time:
  - 80ns at  $V_{CC} = 3.0V$  to 3.6V
  - 100ns at  $V_{CC} = 2.7V$  to 3.6V
- Pin compatible with M27C801
- Low power consumption:
  - 30 $\mu$ A max Standby Current
  - 15mA max Active Current at 5MHz
- Programming time 50 $\mu$ s/Byte
- High reliability CMOS technology
  - 2,000V ESD Protection
  - 200mA Latchup Protection Immunity
- Electronic signature
  - Manufacturer Code: 20h
  - Device Code: 42h
- ECOPACK® packages available



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# 1 Summary description

The M27W801 is a low voltage 8 Mbit EPROM offered in the two ranges UV (ultra violet erase) and OTP (one time programmable). It is ideally suited for microprocessor systems requiring large data or program storage and is organized as 1,048,576 by 8 bits.

The M27W801 operates in the read mode with a supply voltage as low as 2.7V at  $-40$  to  $85^{\circ}\text{C}$  temperature range. The decrease in operating power allows either a reduction of the size of the battery or an increase in the time between battery recharges.

The FDIP32W (window ceramic frit-seal package) has a transparent lids which allow the user to expose the chip to ultraviolet light to erase the bit pattern. A new pattern can then be written to the device by following the programming procedure.

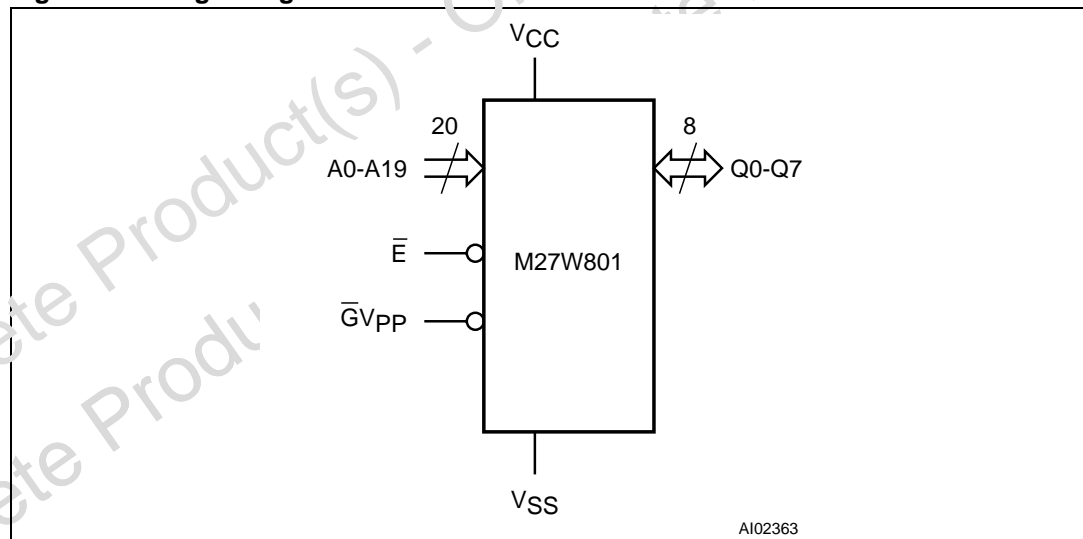
For applications where the content is programmed only one time and erasure is not required, the M27W801 is offered in PDIP32, PLCC32 and TSOP32 (8 x 20 mm) packages.

In order to meet environmental requirements, ST offers the M27W801 in ECOPACK® packages.

ECOPACK packages are Lead-free. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label.

ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

**Figure 1. Logic diagram**



**Table 1. Signal names**

A0-A19	Address Inputs
Q0-Q7	Data Outputs
$\bar{E}$	Chip Enable
$\bar{G}V_{PP}$	Output Enable / Program Supply
$V_{CC}$	Supply Voltage
$V_{SS}$	Ground

Figure 2. DIP connections

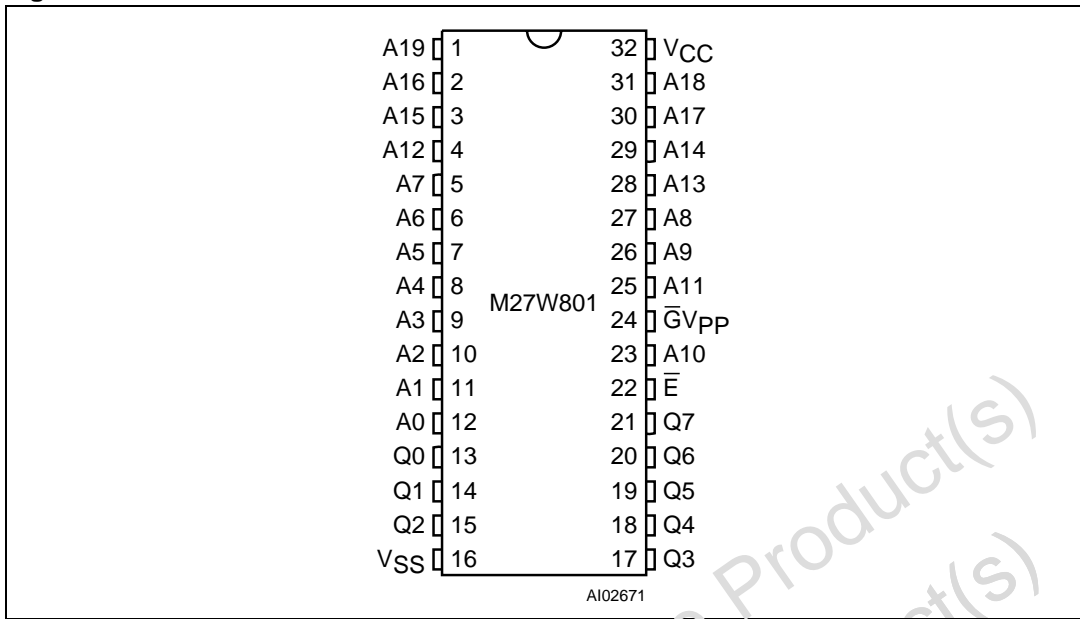


Figure 3. PLCC connections

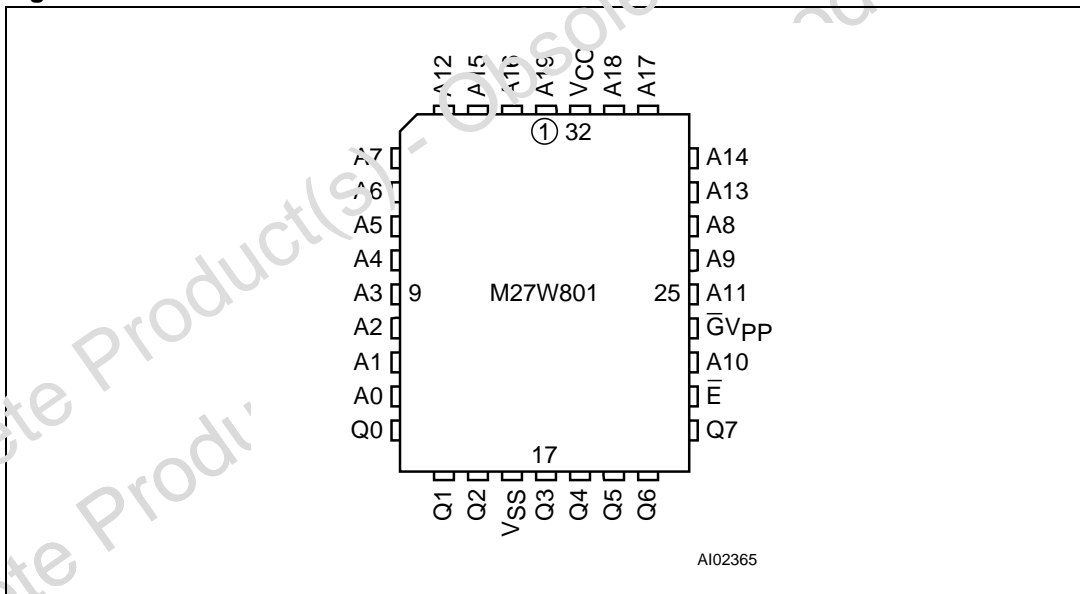
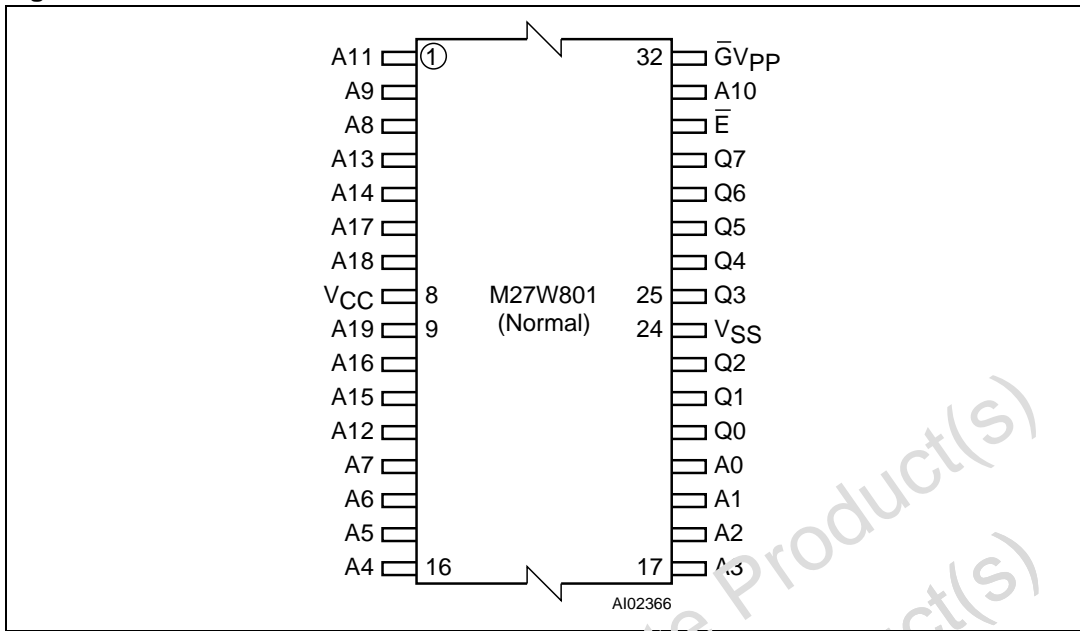


Figure 4. TSOP connections



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## 2 Device operation

The operating modes of the M27W801 are listed in the Operating Modes table. A single power supply is required in the read mode. All inputs are TTL levels except for  $\overline{G}V_{PP}$  and 12V on A9 for Electronic Signature and Margin Mode Set or Reset.

### 2.1 Read mode

The M27W801 has two control functions, both of which must be logically active in order to obtain data at the outputs. Chip Enable ( $\overline{E}$ ) is the power control and should be used for device selection. Output Enable ( $\overline{G}$ ) is the output control and should be used to gate data to the output pins, independent of device selection. Assuming that the addresses are stable, the address access time ( $t_{AVQV}$ ) is equal to the delay from  $\overline{E}$  to output ( $t_{ELQV}$ ). Data is available at the output after a delay of  $t_{GLQV}$  from the falling edge of  $\overline{G}$ , assuming that  $\overline{E}$  has been low and the addresses have been stable for at least  $t_{AVQV} - t_{GLQV}$ .

### 2.2 Standby mode

The M27W801 has a standby mode which reduces the supply current from 15mA to 20 $\mu$ A with low voltage operation  $V_{CC} \leq 3.6V$ , see Read mode DC Characteristics table for details. The M27W801 is placed in the standby mode by applying a CMOS high signal to the  $\overline{E}$  input. When in the standby mode, the outputs are in a high impedance state, independent of the  $\overline{G}V_{PP}$  input.

### 2.3 Two Line Output Control

Because EPROMs are usually used in larger memory arrays, the product features a 2 line control function which accommodates the use of multiple memory connection. The two line control function allows:

- the lowest possible memory power dissipation
- complete assurance that output bus contention will not occur

For the most efficient use of these two control lines,  $\overline{E}$  should be decoded and used as the primary device selecting function, while  $\overline{G}$  should be made a common connection to all devices in the array and connected to the  $\overline{READ}$  line from the system control bus. This ensures that all deselected memory devices are in their low power standby mode and that the output pins are only active when data is required from a particular memory device.

## 2.4 System considerations

The power switching characteristics of Advanced CMOS EPROMs require careful decoupling of the devices. The supply current,  $I_{CC}$ , has three segments that are of interest to the system designer: the standby current level, the active current level, and transient current peaks that are produced by the falling and rising edges of  $\bar{E}$ . The magnitude of the transient current peaks is dependent on the capacitive and inductive loading of the device at the output. The associated transient voltage peaks can be suppressed by complying with the two line output control and by properly selected decoupling capacitors. It is recommended that a 0.1  $\mu$ F ceramic capacitor be used on every device between  $V_{CC}$  and  $V_{SS}$ . This should be a high frequency capacitor of low inherent inductance and should be placed as close to the device as possible. In addition, a 4.7  $\mu$ F bulk electrolytic capacitor should be used between  $V_{CC}$  and  $V_{SS}$  for every eight devices. The bulk capacitor should be located near the power supply connection point. The purpose of the bulk capacitor is to overcome the voltage drop caused by the inductive effects of PCB traces.

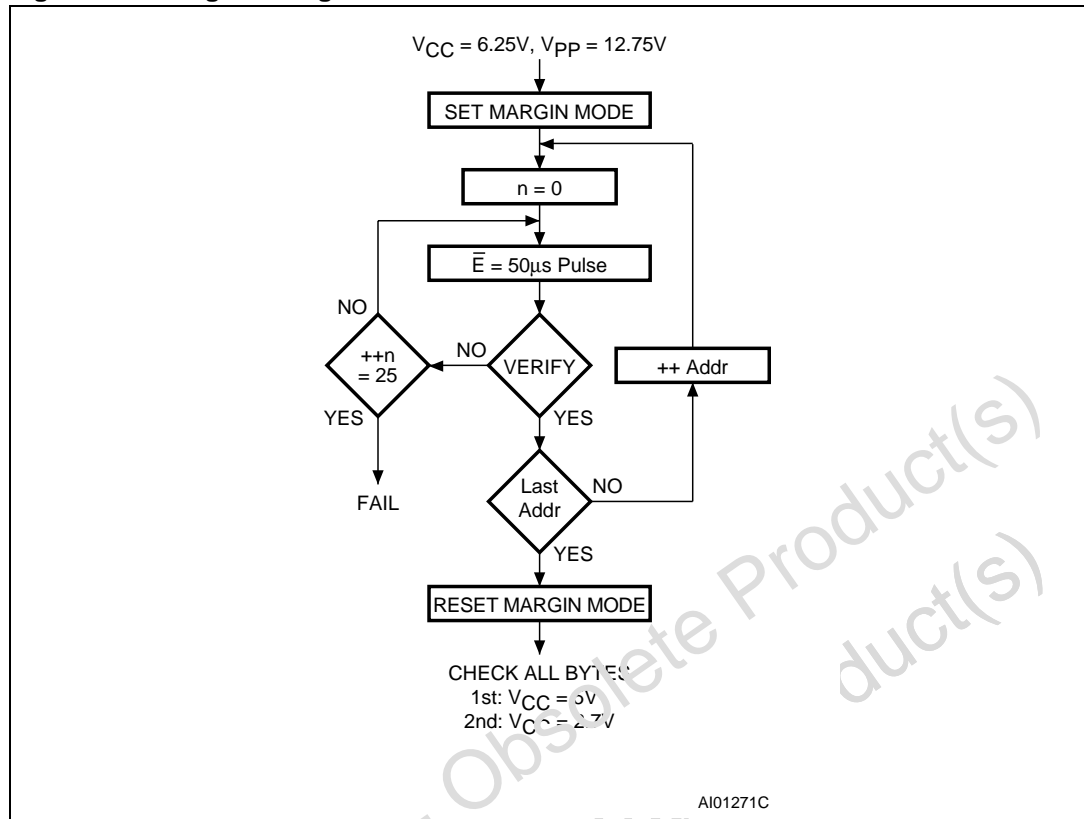
## 2.5 Programming

The M27W801 has been designed to be fully compatible with the M27C801 and has the same electronic signature. As a result the M27W801 can be programmed as the M27C801 on the same programming equipment applying 12.75V on  $V_{PP}$  and 6.25V on  $V_{CC}$  by the use of the same PRESTO IIB algorithm. When delivered (and after each '1's erasure for UV EPROM), all bits of the M27W801 are in the "1" state. Data is introduced by selectively programming "0"s into the desired bit locations. Although only '0' will be programmed, both "1" and "0" can be present in the data word. The only way to change a '0' to a '1' is by die exposure to ultraviolet light (UV EPROM). The M27W801 is in the programming mode when  $V_{PP}$  input is at 12.75V and  $\bar{E}$  is pulsed to  $V_{IL}$ . The data to be programmed is applied to 8 bits in parallel to the data output pins. The levels required for the address and data inputs are TTL.  $V_{CC}$  is specified to be 6.25V  $\pm$  0.25V.

## 2.6 PRESTO IIB programming algorithm

PRESTO IIB Programming Algorithm allows the whole array to be programmed with a guaranteed margin, in a typical time of 52.5 seconds. This can be achieved with STMicroelectronics M27W801 due to several design innovations to improve programming efficiency and to provide adequate margin for reliability. Before starting the programming the internal MARGIN MODE circuit must be set in order to guarantee that each cell is programmed with enough margin. Then a sequence of 50  $\mu$ s program pulses are applied to each byte until a correct verify occurs (see [Figure 5](#)). No overprogram pulses are applied since the verify in MARGIN MODE at  $V_{CC}$  much higher than 3.6V, provides the necessary margin.

Figure 5. Programming flowchart



## 2.7 Program Inhibit

Programming of multiple M27W801s in parallel with different data is also easily accomplished. Except for  $\bar{E}$ , all like inputs including  $\bar{G}$  and  $V_{PP}$  of the parallel M27W801 may be common. A TTL low level pulse applied to a M27W801's  $\bar{E}$  input, with  $V_{PP}$  at 12.75V, will program that M27W801. A high level  $\bar{E}$  input inhibits the other M27W801s from being programmed.

## 2.5 Program Verify

A verify (read) should be performed on the programmed bits to determine that they were correctly programmed. The verify is accomplished with  $\bar{G}$  at  $V_{IL}$ . Data should be verified with  $t_{ELQV}$  after the falling edge of  $\bar{E}$ .

## 2.9 Electronic signature

The Electronic Signature (ES) mode allows the reading out of a binary code from an EPROM that will identify its manufacturer and type. This mode is intended for use by programming equipment to automatically match the device to be programmed with its corresponding programming algorithm. The ES mode is functional in the  $25^{\circ}\text{C} \pm 5^{\circ}\text{C}$  ambient temperature range that is required when programming the M27W801. To activate the ES mode, the programming equipment must force 11.5V to 12.5V on address line A9 of the M27W801. Two identifier bytes may then be sequenced from the device outputs by toggling address line A0 from  $V_{IL}$  to  $V_{IH}$ . All other address lines must be held at  $V_{IL}$  during Electronic Signature mode.

Byte 0 ( $A0 = V_{IL}$ ) represents the manufacturer code and byte 1 ( $A0 = V_{IH}$ ) the device identifier code. For the STMicroelectronics M27W801, these two identifier bytes are given in [Table 3](#) and can be read-out on outputs Q7 to Q0.

Note that the M27W801 and M27C801 have the same identifier byte.

## 2.10 Erasure operation (applies to UV EPROM)

The erasure characteristics of the M27W801 is such that erasure begins when the cells are exposed to light with wavelengths shorter than approximately 4000 Å. It should be noted that sunlight and some type of fluorescent lamps have wavelengths in the 3000-4000 Å range.

Research shows that constant exposure to room level fluorescent lighting could erase a typical M27W801 in about 3 years, while it would take approximately 1 week to cause erasure when exposed to direct sunlight. If the M27W801 is to be exposed to these types of lighting conditions for extended periods of time, it is suggested that opaque labels be put over the M27W801 window to prevent unintentional erasure. The recommended erasure procedure for the M27W801 is exposure to short wave ultraviolet light which has wavelength 2537 Å. The integrated dose (i.e. UV intensity x exposure time) for erasure should be a minimum of 30 W-sec/cm<sup>2</sup>. The erasure time with this dosage is approximately 30 to 40 minutes using an ultraviolet lamp with 12000  $\mu\text{W}/\text{cm}^2$  power rating. The M27W801 should be placed within 2.5 cm (1 inch) of the lamp tubes during the erasure. Some lamps have a filter on their tubes which should be removed before erasure.

**Table 2. Operating modes<sup>(1)</sup>**

Mode	$\bar{E}$	$\bar{G}V_{PP}$	A9	Q7-Q0
Read	$V_{IL}$	$V_{IL}$	X	Data Out
Output Disable	$V_{IL}$	$V_{IH}$	X	Hi-Z
Program	$V_{IL}$ Pulse	$V_{PP}$	X	Data In
Program Inhibit	$V_{IH}$	$V_{PP}$	X	Hi-Z
Standby	$V_{IH}$	X	X	Hi-Z
Electronic Signature	$V_{IL}$	$V_{IL}$	$V_{ID}$	Codes

1. X =  $V_{IH}$  or  $V_{IL}$ ,  $V_{ID} = 12\text{V} \pm 0.5\text{V}$ .

**Table 3. Electronic signature**

Identifier	A0	Q7	Q6	Q5	Q4	Q3	Q2	Q1	Q0	Hex Data
Manufacturer's Code	V <sub>IL</sub>	0	0	1	0	0	0	0	0	20h
Device Code	V <sub>IH</sub>	0	1	0	0	0	0	1	0	42h

### 3 Maximum rating

Stressing the device above the rating listed in the Absolute Maximum Ratings table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

**Table 4. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
T <sub>A</sub>	Ambient Operating Temperature <sup>(1)</sup>	-40 to 125	°C
T <sub>BIAS</sub>	Temperature Under Bias	-50 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C
V <sub>IO</sub> <sup>(2)</sup>	Input or Output Voltage (except A9)	-2 to 7	V
V <sub>CC</sub>	Supply Voltage	-2 to 7	V
V <sub>A9</sub> <sup>(2)</sup>	A9 Voltage	-2 to 13.5	V
V <sub>PP</sub>	Program Supply Voltage	-2 to 14	V

1. Depends on range.

2. Minimum DC voltage on Input or Output is -0.5V with possible undershoot to -2.0V for a period less than 20ns. Maximum DC voltage on Output is V<sub>CC</sub> +0.5V with possible overshoot to V<sub>CC</sub> +2V for a period less than 20ns.

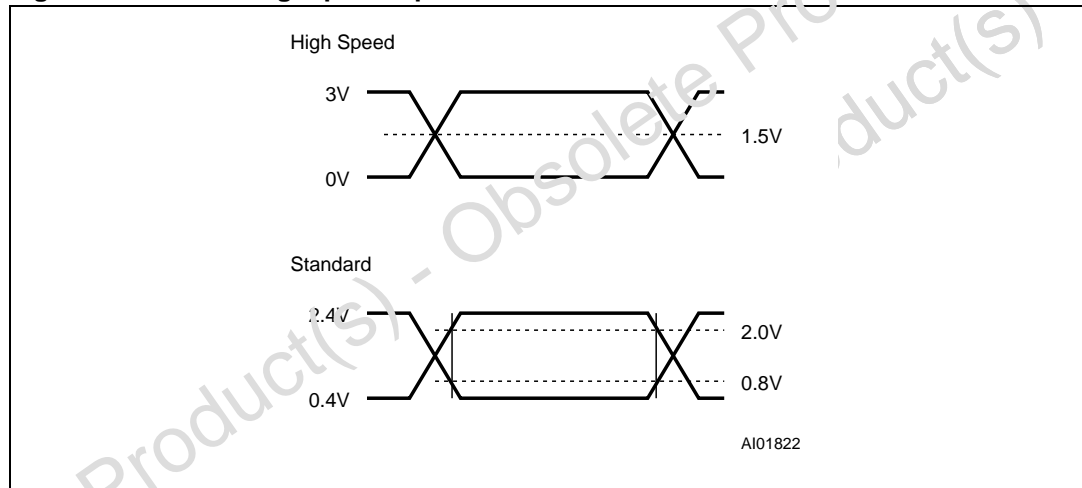
## 4 DC and AC parameters

This section summarizes the operating and measurement conditions, and the DC and AC characteristics of the device. The parameters in the DC and AC Characteristic tables that follow are derived from tests performed under the Measurement Conditions summarized in the relevant tables. Designers should check that the operating conditions in their circuit match the measurement conditions when relying on the quoted parameters.

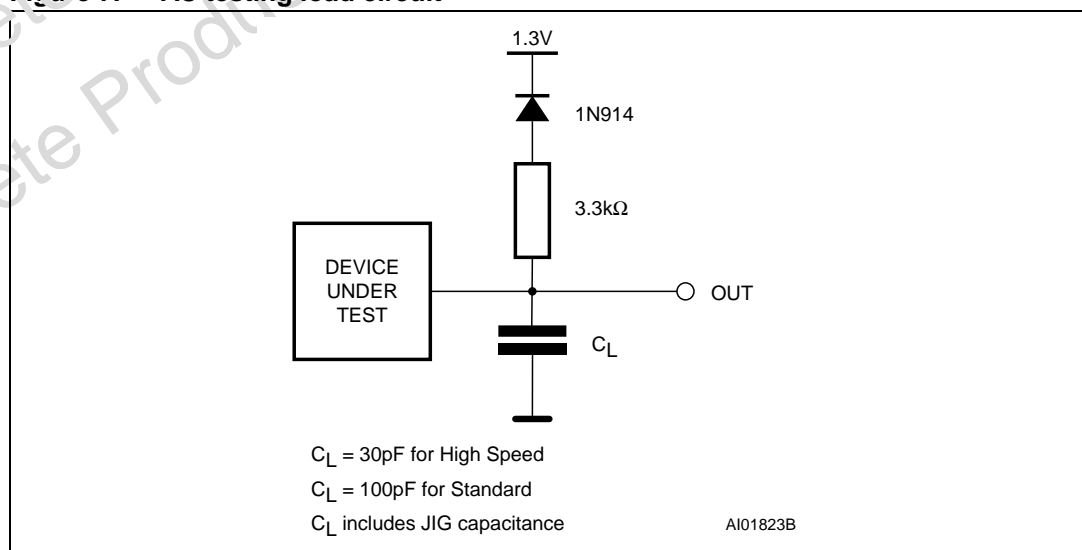
**Table 5. AC measurement conditions**

	High Speed	Standard
Input Rise and Fall Times	$\leq 10\text{ns}$	$\leq 20\text{ns}$ (10% to 90%)
Input Pulse Voltages	0 to 3V	0.4V to 2.4V
Input and Output Timing Ref. Voltages	1.5V	0.3V and 2V

**Figure 6. AC testing input output waveform**



**Figure 7. AC testing load circuit**



**Table 6. Capacitance<sup>(1) (2)</sup>**

Symbol	Parameter	Test Condition	Min	Max	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V		6	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0V		12	pF

1. T<sub>A</sub> = 25 °C, f = 1 MHz
2. Sampled only, not 100% tested.

**Table 7. Read mode DC characteristics<sup>(1) (2)</sup>**

Symbol	Parameter	Test Condition	Min	Max	Unit
I <sub>LI</sub>	Input Leakage Current	0V ≤ V <sub>IN</sub> ≤ V <sub>CC</sub>		±10	µA
I <sub>LO</sub>	Output Leakage Current	0V ≤ V <sub>OUT</sub> ≤ V <sub>CC</sub>		±10	µA
I <sub>CC</sub>	Supply Current	$\bar{E} = V_{IL}, \bar{G}V_{PP} = V_{IL},$ I <sub>OUT</sub> = 0mA, f = 5MHz, V <sub>CC</sub> ≤ 3.6V		15	mA
I <sub>CC1</sub>	Supply Current (Standby) TTL	$\bar{E} = V_{IH}$		1	mA
I <sub>CC2</sub>	Supply Current (Standby) CMOS	$\bar{E} > V_{CC} - 0.2V,$ V <sub>CC</sub> ≤ 6V		30	µA
I <sub>PP</sub>	Program Current	V <sub>PP</sub> = V <sub>CC</sub>		10	µA
V <sub>IL</sub>	Input Low Voltage		-0.6	0.2 V <sub>CC</sub>	V
V <sub>IH</sub> <sup>(3)</sup>	Input High Voltage		0.7 V <sub>CC</sub>	V <sub>CC</sub> + 0.5	V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 2.1mA		0.4	V
V <sub>OH</sub>	Output High Voltage TTL	I <sub>OH</sub> = -1mA	2.4		V

1. T<sub>A</sub> = -40 to 85 °C; V<sub>CC</sub> = 2.7V to 3.6V; V<sub>PP</sub> = V<sub>CC</sub>
2. V<sub>CC</sub> must be applied simultaneously with or before V<sub>PP</sub> and removed simultaneously or after V<sub>PP</sub>.
3. Maximum DC voltage on Output is V<sub>CC</sub>+0.5V.

**Table 8. Programming mode DC characteristics<sup>(1) (2)</sup>**

Symbol	Parameter	Test Condition	Min	Max	Unit
I <sub>LI</sub>	Input Leakage Current	V <sub>IL</sub> ≤ V <sub>IN</sub> ≤ V <sub>IH</sub>		±10	µA
I <sub>CC</sub>	Supply Current			50	mA
I <sub>PP</sub>	Program Current	$\bar{E} = V_{IL}$		50	mA
V <sub>IL</sub>	Input Low Voltage		-0.3	0.8	V
V <sub>IH</sub>	Input High Voltage		2	V <sub>CC</sub> + 0.5	V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 2.1mA		0.4	V
V <sub>OH</sub>	Output High Voltage TTL	I <sub>OH</sub> = -1mA	3.6		V
V <sub>ID</sub>	A9 Voltage		11.5	12.5	V

1. T<sub>A</sub> = 25 °C; V<sub>CC</sub> = 6.25V ± 0.25V; V<sub>PP</sub> = 12.75V ± 0.25V
2. V<sub>CC</sub> must be applied simultaneously with or before V<sub>PP</sub> and removed simultaneously or after V<sub>PP</sub>.

Figure 8. Read mode AC waveforms

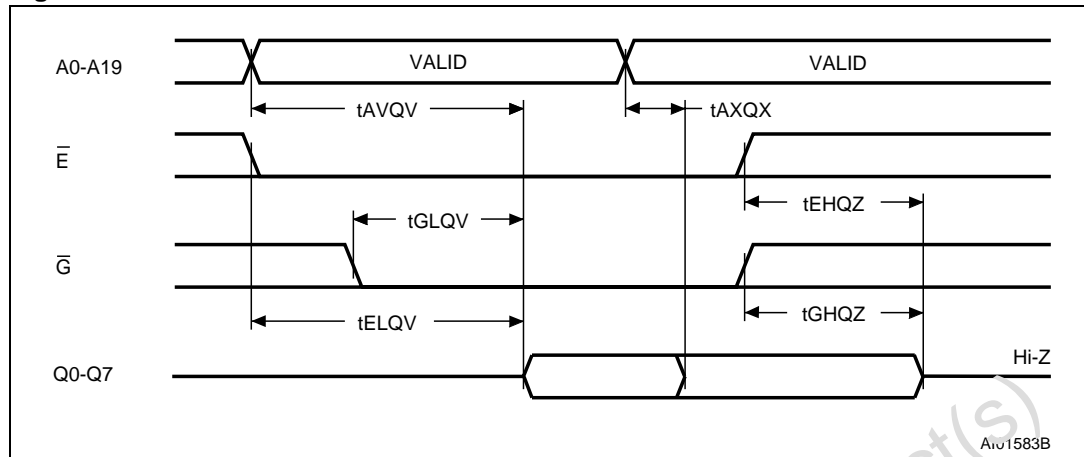
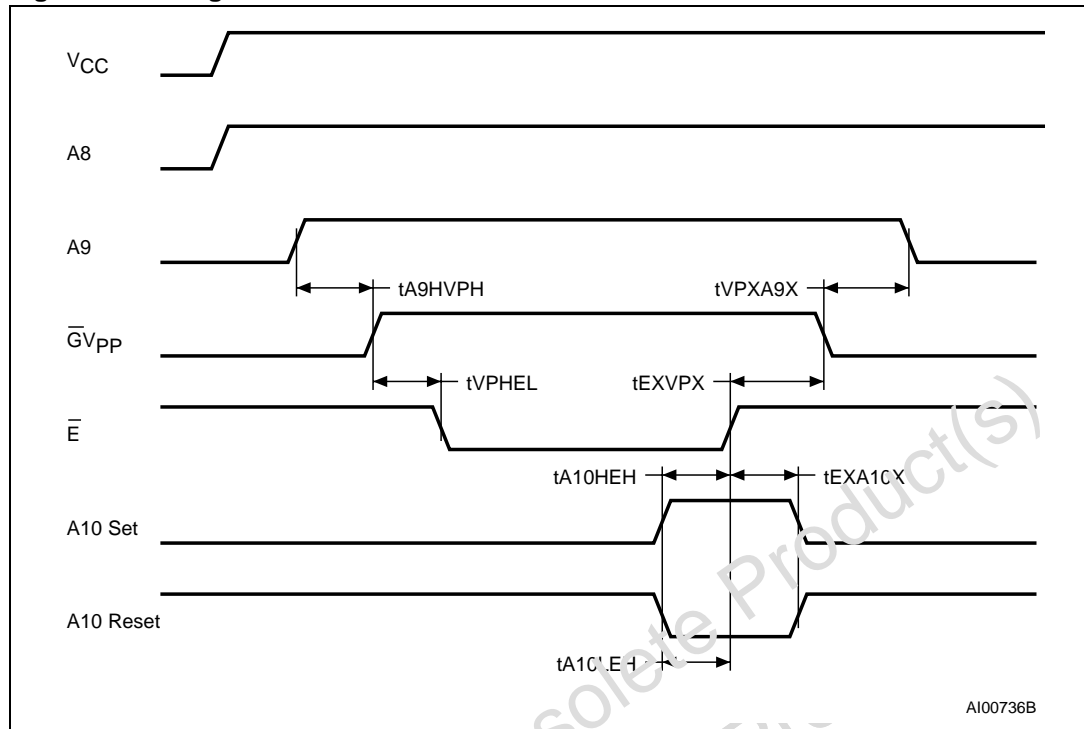


Table 9. Read mode AC characteristics<sup>(1) (2)</sup>

Symbol	Alt	Parameter	Test Condition	M27W801						Unit
				-100 <sup>(3)</sup>				-120 (-150/-200)		
				$V_{CC} = 3.0V$ to 3.5v		$V_{CC} = 2.7V$ to 3.6V		$V_{CC} = 2.7V$ to 3.6V		
				Min	Max	Min	Max	Min	Max	
$t_{AVQV}$	$t_{ACC}$	Address Valid to Output Valid	$\bar{E} = V_{IL}, \bar{G} = V_{IL}$		80		100		120	ns
$t_{ELQV}$	$t_{CE}$	Chip Enable Low to Output Valid	$\bar{G} = V_{IL}$		80		100		120	ns
$t_{GLQV}$	$t_{OE}$	Output Enable Low to Output Valid	$\bar{E} = V_{IL}$		50		60		70	ns
$t_{EHQZ}^{(4)}$	$t_{DF}$	Chip Enable High to Output Hi-Z	$\bar{G} = V_{IL}$	0	50	0	60	0	70	ns
$t_{GHQZ}^{(4)}$	$t_{DF}$	Output Enable High to Output Hi-Z	$\bar{E} = V_{IL}$	0	50	0	60	0	70	ns
$t_{AXQX}$	$t_{OH}$	Address Transition to Output Transition	$\bar{E} = V_{IL}, \bar{G} = V_{IL}$	0		0		0		ns

1.  $T_A = -40$  to  $85$  °C;  $V_{CC} = 2.7V$  to  $3.6V$ ;  $V_{PP} = V_{CC}$
2.  $V_{CC}$  must be applied simultaneously with or before  $V_{PP}$  and removed simultaneously or after  $V_{PP}$ .
3. Speed obtained with High Speed AC measurement conditions.
4. Sampled only, not 100% tested.

Figure 9. Margin mode AC waveforms



1. A8 High level = 5V; A9 High level = 12V.

Table 10. Margin mode AC characteristics<sup>(1) (2)</sup>

Symbol	Alt	Parameter	Test Condition	Min	Max	Unit
t <sub>A9HVP</sub>	t <sub>AS9</sub>	V <sub>A9</sub> High to V <sub>PP</sub> High		2		μs
t <sub>VPHE</sub>	t <sub>VPS</sub>	V <sub>PP</sub> High to Chip Enable Low		2		μs
t <sub>A10HEH</sub>	t <sub>AS10</sub>	V <sub>A10</sub> High to Chip Enable High (Set)		1		μs
t <sub>A10LEH</sub>	t <sub>AS10</sub>	V <sub>A10</sub> Low to Chip Enable High (Reset)		1		μs
t <sub>EXA10X</sub>	t <sub>AH10</sub>	Chip Enable Transition to V <sub>A10</sub> Transition		1		μs
t <sub>EXVPX</sub>	t <sub>VPH</sub>	Chip Enable Transition to V <sub>PP</sub> Transition		2		μs
t <sub>VPXA9X</sub>	t <sub>AH9</sub>	V <sub>PP</sub> Transition to V <sub>A9</sub> Transition		2		μs

1. T<sub>A</sub> = 25 °C; V<sub>CC</sub> = 6.25V ± 0.25V; V<sub>PP</sub> = 12.75V ± 0.25V

2. V<sub>CC</sub> must be applied simultaneously with or before V<sub>PP</sub> and removed simultaneously or after V<sub>PP</sub>.

Figure 10. Programming and Verify modes AC waveforms

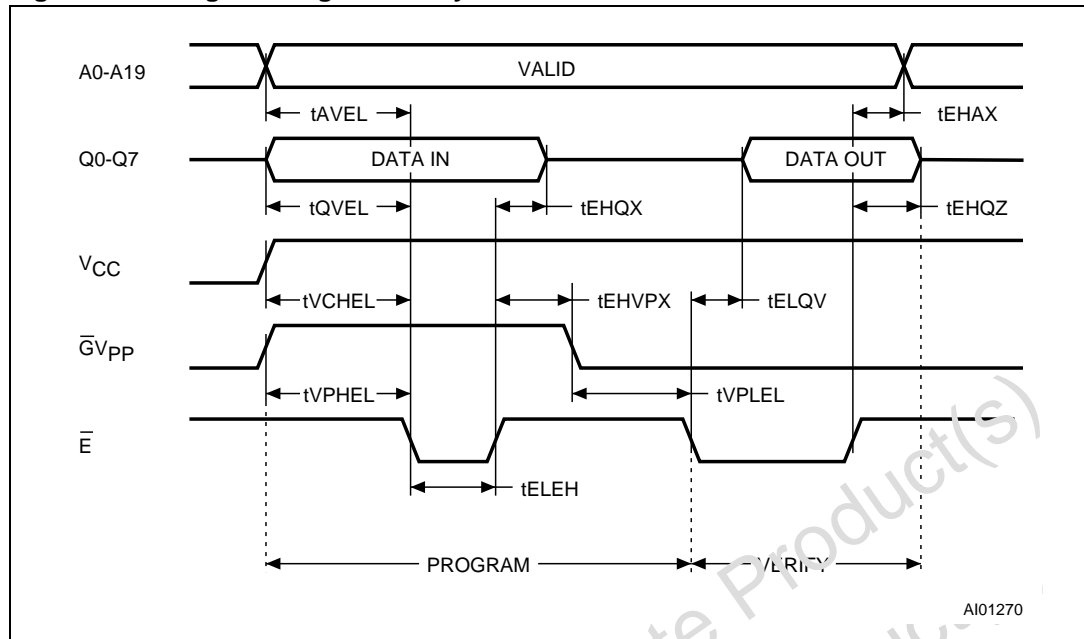


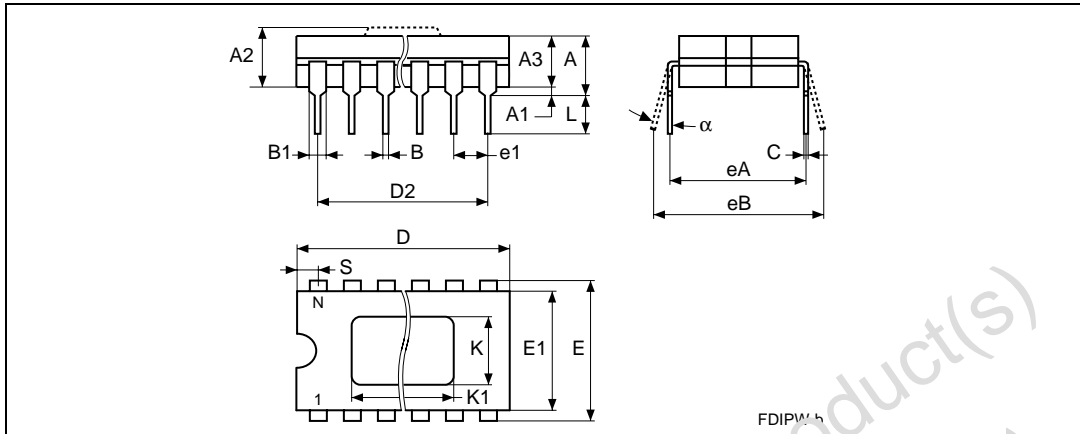
Table 11. Programming mode AC characteristics (1) (2)

Symbol	Alt	Parameter	Test Condition	Min	Max	Unit
t <sub>AVEL</sub>	t <sub>AS</sub>	Address Valid to Chip Enable Low		2		μs
t <sub>QVEL</sub>	t <sub>DS</sub>	Input Valid to Chip Enable Low		2		μs
t <sub>VCHL</sub>	t <sub>VCS</sub>	V <sub>CC</sub> High to Chip Enable Low		2		μs
t <sub>VPHEL</sub>	t <sub>OES</sub>	V <sub>PP</sub> High to Chip Enable Low		2		μs
t <sub>VPLVPH</sub>	t <sub>PR</sub>	V <sub>PP</sub> Rise Time		50		ns
t <sub>ELEH</sub>	t <sub>PW</sub>	Chip Enable Program Pulse Width (Initial)		45	55	μs
t <sub>EHQX</sub>	t <sub>DH</sub>	Chip Enable High to Input Transition		2		μs
t <sub>EHVPX</sub>	t <sub>OEH</sub>	Chip Enable High to V <sub>PP</sub> Transition		2		μs
t <sub>VPLEL</sub>	t <sub>VR</sub>	V <sub>PP</sub> Low to Chip Enable Low		2		μs
t <sub>ELQV</sub>	t <sub>DV</sub>	Chip Enable Low to Output Valid			1	μs
t <sub>EHQZ</sub> <sup>(3)</sup>	t <sub>DFP</sub>	Chip Enable High to Output Hi-Z		0	130	ns
t <sub>EHAX</sub>	t <sub>AH</sub>	Chip Enable High to Address Transition		0		ns

1. T<sub>A</sub> = 25 °C; V<sub>CC</sub> = 6.25V ± 0.25V; V<sub>PP</sub> = 12.75V ± 0.25V
2. V<sub>CC</sub> must be applied simultaneously with or before V<sub>PP</sub> and removed simultaneously or after V<sub>PP</sub>.
3. Sampled only, not 100% tested.

## 5 Package mechanical

Figure 11. FDIP32W - 32 pin Ceramic Frit-seal DIP with window, package outline

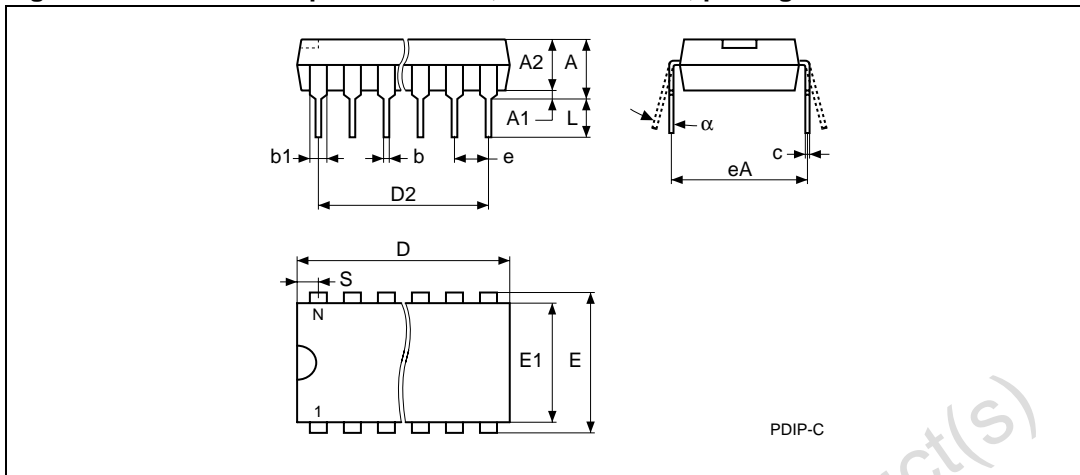


1. Drawing is not to scale.

Table 12. FDIP32WC - 32 pin Ceramic Frit-seal DIP, with window (0.260" x 0.420"), package mechanical data

Symbol	millimeters			inches			
	Typ	Min	Max	Typ	Min	Max	
A			5.72			0.225	
A1		0.51	1.40		0.020	0.055	
A2		3.91	4.57		0.154	0.180	
A3		3.89	4.50		0.153	0.177	
B		0.41	0.56		0.016	0.022	
E1	1.45	–	–	0.057	–	–	
C		0.23	0.30		0.009	0.012	
D		41.73	42.04		1.643	1.655	
D2	38.10	–	–	1.500	–	–	
e	2.54	–	–	0.100	–	–	
eA	14.99	–	–	0.590	–	–	
eB		16.18	18.03		0.637	0.710	
E	15.24	–	–	0.600	–	–	
E1		13.06	13.36		0.514	0.526	
K	6.60	–	–	0.260	–	–	
K1	10.67	–	–	0.420	–	–	
L		3.18	4.10		0.125	0.161	
S		1.52	2.49		0.060	0.098	
α		4°	11°		4°	11°	
N		32				32	

Figure 12. PDIP32 - 32 pin Plastic DIP, 600 mils width, package outline

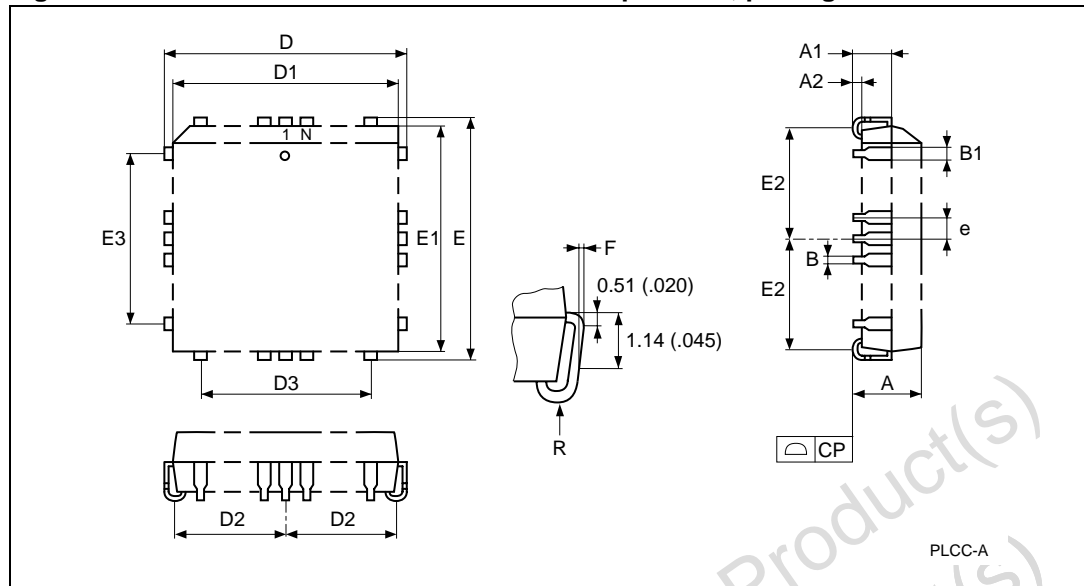


1. Drawing is not to scale.

Table 13. PDIP32 – 32 pin Plastic DIP, 600 mils width, package mechanical data

Symbol	millimeters			inches		
	Typ	Min	Max	Typ	Min	Max
A			4.33			0.190
A1		0.38			0.015	
A2	3.81			0.150		
b		0.41	0.53		0.016	0.021
b1		1.14	1.65		0.045	0.065
c		0.23	0.38		0.009	0.015
D		41.78	42.29		1.645	1.665
D2	38.10	–	–	1.500	–	–
eA	15.24	–	–	0.600	–	–
e	2.54	–	–	0.100	–	–
E		15.24	15.88		0.600	0.625
E1		13.46	13.97		0.530	0.550
S		1.65	2.21		0.065	0.087
L		3.05	3.56		0.120	0.140
alpha		0°	15°		0°	15°
N		32			32	

Figure 13. PLCC32 - 32 lead Plastic Leaded Chip Carrier, package outline

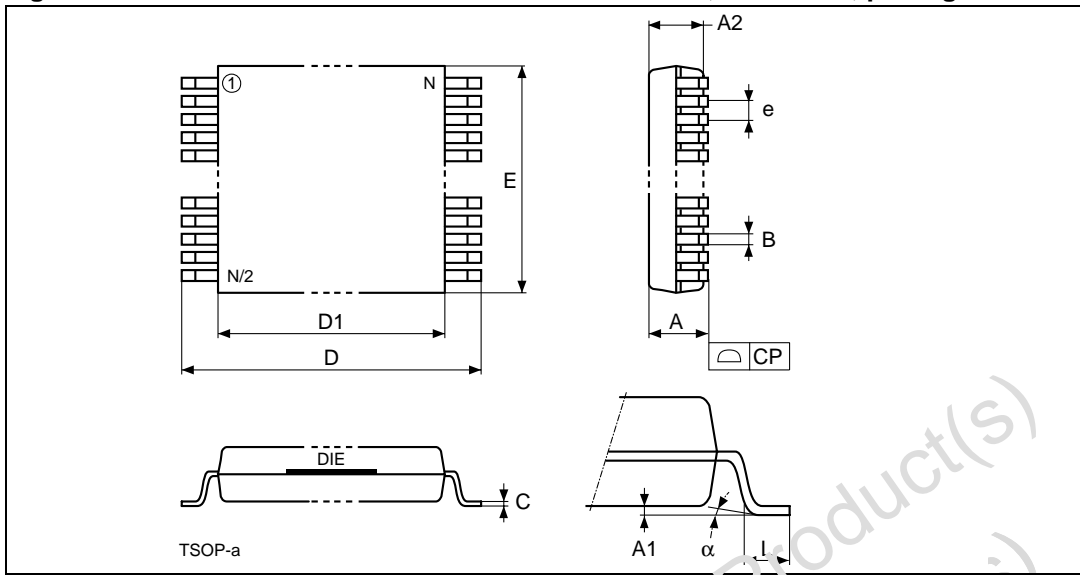


1. Drawing is not to scale.

Table 14. PLCC32 - 32 lead Plastic Leaded Chip Carrier, package mechanical data

Symbol	millimeters			inches			
	Typ	Min	Max	Typ	Min	Max	
A		3.17	3.56	0.125		0.140	
A1		1.53	2.41	0.060		0.095	
A2		0.38	—	0.015		—	
B		0.33	0.53	0.013		0.021	
B1		0.66	0.81	0.026		0.032	
CP			0.10			0.004	
D		12.32	12.57	0.485		0.495	
D1		11.35	11.51	0.447		0.453	
D2		4.78	5.66	0.188		0.223	
D3	7.62	—	—	0.300	—	—	
E		14.86	15.11	0.585		0.595	
E1		13.89	14.05	0.547		0.553	
E2		6.05	6.93	0.238		0.273	
E3	10.16	—	—	0.400	—	—	
e	1.27	—	—	0.050	—	—	
F		0.00	0.13	0.000		0.005	
R	0.89	—	—	0.035	—	—	
N		32			32		

Figure 14. TSOP32 - 32 lead Plastic Thin Small Outline, 8 x 20 mm, package outline



1. Drawing is not to scale.

Table 15. TSOP32 - 32 lead Plastic Thin Small Outline, 8 x 20 mm, package mechanical data

Symbol	millimeters			inches		
	Typ	Min	Max	Typ	Min	Max
A			1.200			0.0472
A1		0.050	0.150		0.0020	0.0059
A2		0.950	1.050		0.0374	0.0413
B		0.170	0.250		0.0067	0.0098
e		0.100	0.210		0.0039	0.0083
CP			0.100			0.0039
D		19.800	20.200		0.7795	0.7953
D1		18.300	18.500		0.7205	0.7283
e	0.500	–	–	0.0197	–	–
E		7.900	8.100		0.3110	0.3189
L		0.500	0.700		0.0197	0.0276
N		32			32	
α		0°	5°		0°	5°

## 6 Part numbering

**Table 16. Ordering information scheme**

Example:	M27W801	-100	K	6	TR
<b>Device Type</b>	M27				
<b>Supply Voltage</b>	W = 2.7V to 3.6V				
<b>Device Function</b>	801 = 8 Mbit (1Mb x8)				
<b>Speed</b>	-100 <sup>(1),(2)</sup> = 100 ns -120 = 120 ns				
<b>Not For New Design<sup>(3)</sup></b>	-150 = 150 ns -200 = 200 ns				
<b>Package</b>	F = FDIP32W <sup>(4)</sup> B = PDIP32 K = PLCC32 N = TSOP32: 8 x 20 mm <sup>(4)</sup>				
<b>Temperature Range</b>	6 = -40 to 85 °C				
<b>Options</b>	TR = Tape & Reel Packing				

1. High Speed, see AC Characteristics section for further information.
  2. This speed also guarantees 80ns access time at V<sub>CC</sub> = 3.0V to 3.6V.
  3. These speeds are replaced by the 120ns.
  4. Packages option available on request. Please contact STMicroelectronics local Sales Office.
- For a list of available options (Speed, Package, etc...) or for further information on any aspect of this device, please contact the STMicroelectronics Sales Office nearest to you.

## 7 Revision history

**Table 17. Document revision history**

Date	Version	Revision Details
July 1999	1.0	First Issue
15-Mar-2000	1.1	FDIP32W Package Dimension, L Max added ( <a href="#">Table 12.</a> ) TSOP32 Package Dimension changed ( <a href="#">Table 15</a> ) 0 to 70°C Temperature Range removed Programming Time changed
21-Apr-2000	1.2	Read Mode AC Characteristics: $t_{AVQV}$ , $t_{ELQV}$ , $t_{GLQV}$ , $t_{EHQZ}$ , $t_{GHQZ}$ changed ( <a href="#">Table 9</a> )
20-Feb-2002	1.3	PDIP32 Mechanical data and drawing changed ( <a href="#">Table 13</a> ) PLCC32 Mechanical data: A2 clarified ( <a href="#">Table 14</a> ) Read Mode DC Characteristics: $V_{OH}$ clarified ( <a href="#">Table 7</a> )
06-May-2002	1.4	PLCC32 Mechanical data and drawing clarified ( <a href="#">Table 14</a> , <a href="#">Figure 13</a> ) $I_{CC}$ Standby value clarified
21-Mar-2003	1.5	Ordering Information Scheme clarified ( <a href="#">Table 16</a> ) TSOP32 Package Mechanical Data clarified ( <a href="#">Table 15</a> )
22-May-2006	2	Document converted to new template (sections added, information moved). Packages are ECCPACK® compliant. Package specifications updated (see <a href="#">Section 5: Package mechanical</a> ).

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